

# TBB1016

Twin Built in Biasing Circuit MOS FET IC  
VHF/VHF RF Amplifier

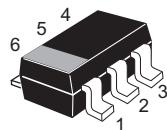
R07DS0318EJ0400  
Rev.4.00  
Jan 10, 2014

## Features

- Small SMD package CMPAK-6 built in twin BBFET; To reduce using parts cost & PC board space.
- Very useful for total tuner cost reduction.
- Suitable for World Standard Tuner RF amplifier.
- High gain; PG = 32 dB at 200 MHz
- Low noise; NF = 1.0 dB at 200 MHz
- Power supply voltage: 5 V

## Outline

RENESAS Package code: PTSP0006JA-A  
(Package name: CMPAK-6)



1. Drain(1)
2. Source
3. Drain(2)
4. Gate-1(2)
5. Gate-2
6. Gate-1(1)

Notes: 1. Marking is "RM".  
2. TBB1016 is individual type number of RENESAS TBBFET.

## Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DS</sub>	6	V
Gate1 to source voltage	V <sub>G1S</sub>	+6 -0	V
Gate2 to source voltage	V <sub>G2S</sub>	+6 -0	V
Drain current	I <sub>D</sub>	30	mA
Channel power dissipation	P <sub>ch</sub> <sup>Note3</sup>	250	mW
Channel temperature	T <sub>ch</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

Note: 3. Value on the glass epoxy board (50 mm × 40 mm × 1 mm)

## Electrical Characteristics

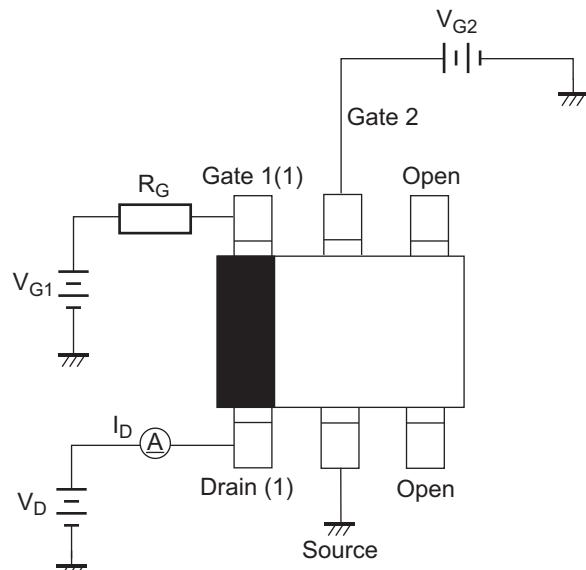
- The below specification are applicable for FET1 and FET2 unit

(Ta = 25°C)

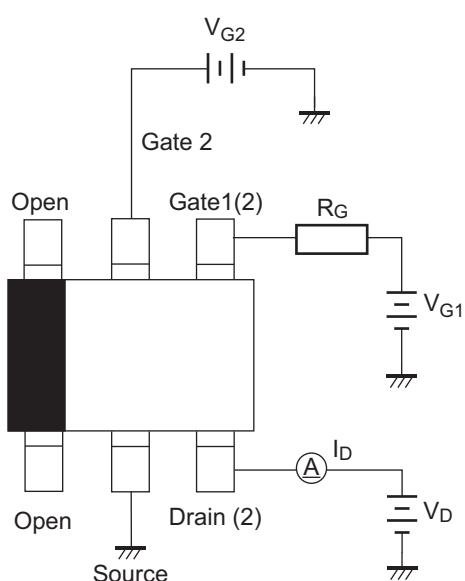
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	6	—	—	V	I <sub>D</sub> = 200 μA, V <sub>G1S</sub> = V <sub>G2S</sub> = 0
Gate1 to source breakdown voltage	V <sub>(BR)G1SS</sub>	+6	—	—	V	I <sub>G1</sub> = +10 μA, V <sub>G2S</sub> = V <sub>DS</sub> = 0
Gate2 to source breakdown voltage	V <sub>(BR)G2SS</sub>	+6	—	—	V	I <sub>G2</sub> = +10 μA, V <sub>G1S</sub> = V <sub>DS</sub> = 0
Gate1 to source cutoff current	I <sub>G1SS</sub>	—	—	+100	nA	V <sub>G1S</sub> = +5 V, V <sub>G2S</sub> = V <sub>DS</sub> = 0
Gate2 to source cutoff current	I <sub>G2SS</sub>	—	—	+100	nA	V <sub>G2S</sub> = +5 V, V <sub>G1S</sub> = V <sub>DS</sub> = 0
Gate1 to source cutoff voltage	V <sub>G1S(off)</sub>	0.5	0.8	1.1	V	V <sub>DS</sub> = 5 V, V <sub>G2S</sub> = 4 V, I <sub>D</sub> = 100 μA
Gate2 to source cutoff voltage	V <sub>G2S(off)</sub>	0.4	0.7	1.0	V	V <sub>DS</sub> = 5 V, V <sub>G1S</sub> = 5 V, I <sub>D</sub> = 100 μA
Drain current	I <sub>D(op)</sub>	11	15	19	mA	V <sub>DS</sub> = 5 V, V <sub>G1</sub> = 5 V V <sub>G2S</sub> = 4 V, R <sub>G</sub> = 120 kΩ
Forward transfer admittance	y <sub>fs</sub>	30	35	42	mS	V <sub>DS</sub> = 5 V, V <sub>G1</sub> = 5 V, V <sub>G2S</sub> = 4 V, f = 1 kHz, R <sub>G</sub> = 120 kΩ
Input capacitance	C <sub>iss</sub>	1.8	2.2	2.6	pF	V <sub>DS</sub> = 5 V, V <sub>G1</sub> = 5 V, V <sub>G2S</sub> = 4 V, f = 1 MHz, R <sub>G</sub> = 120 kΩ
Output capacitance	C <sub>oss</sub>	0.9	1.3	1.7	pF	
Power gain	PG	27	32	37	dB	V <sub>DS</sub> = 5 V, V <sub>G1</sub> = 5 V, V <sub>G2S</sub> = 4 V, R <sub>G</sub> = 120 kΩ, f = 200 MHz
Noise figure	NF	—	1.0	1.7	dB	

DC Biasing Circuit for Operating Characteristic Items ( $I_{D(\text{op})}$ ,  $|y_{fs}|$ ,  $C_{iss}$ ,  $C_{oss}$ ,  $NF$ ,  $PG$ )

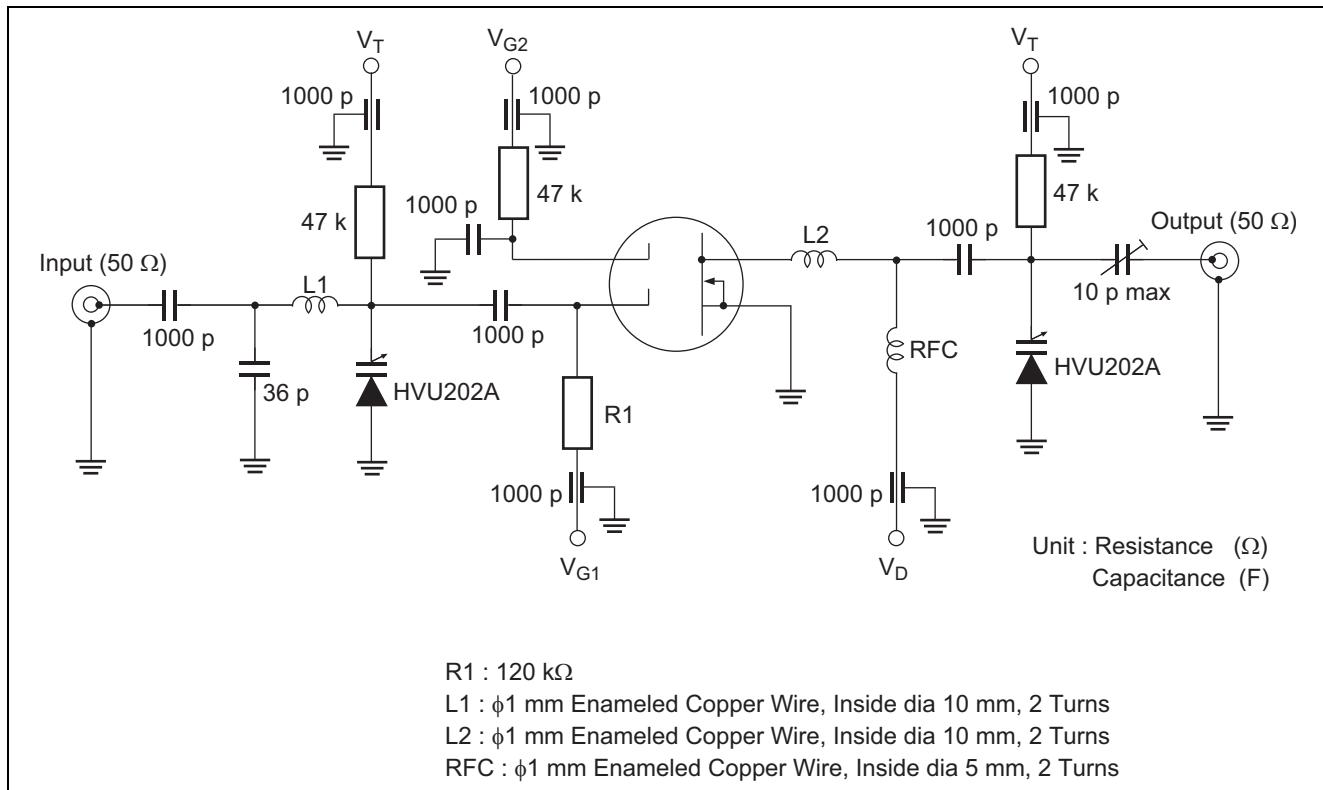
## • Measurement of FET1



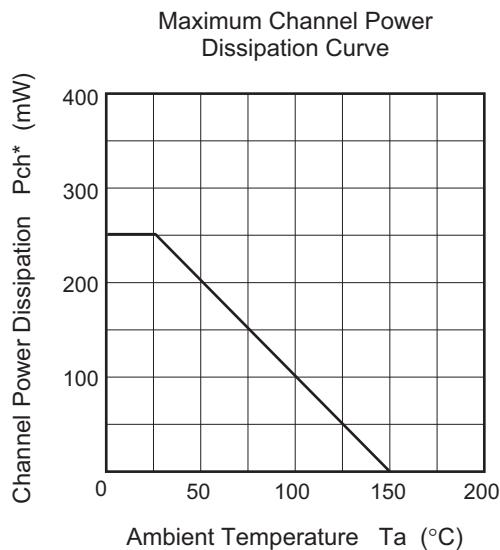
## • Measurement of FET2



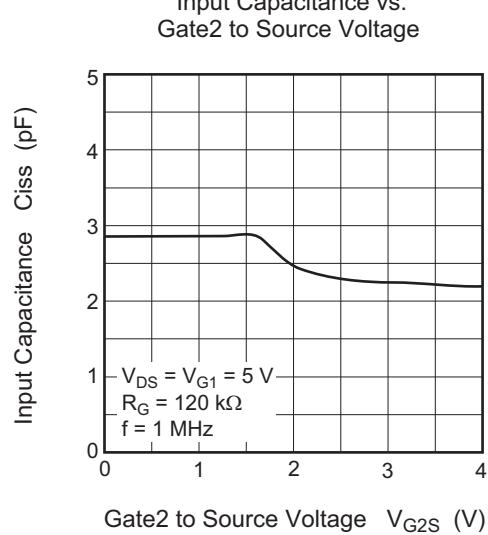
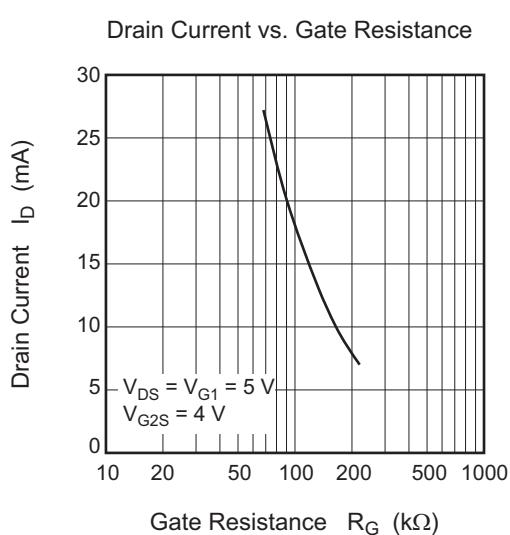
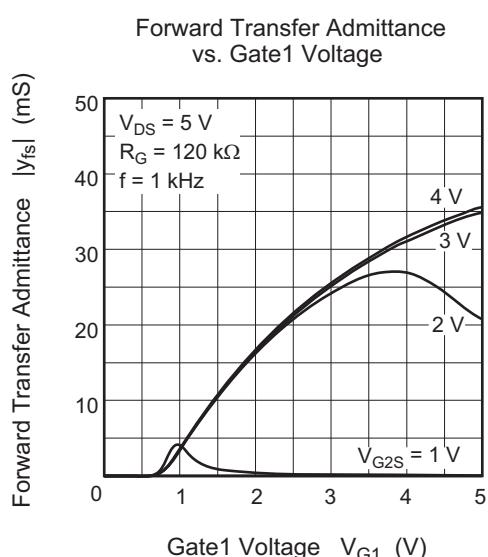
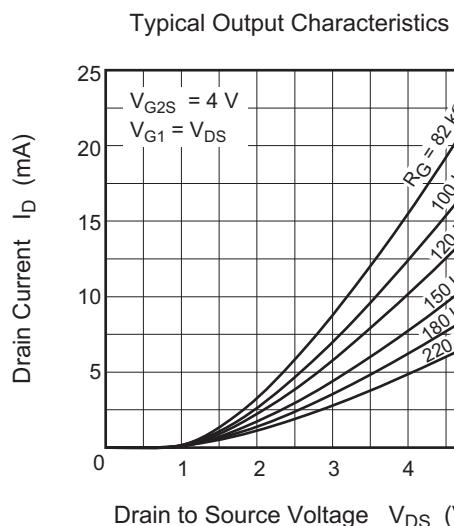
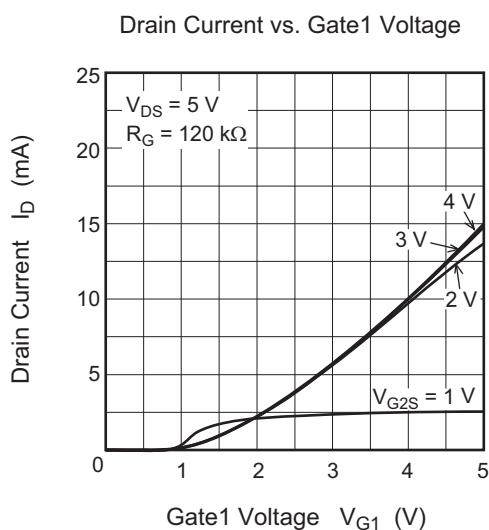
## 200 MHz Power Gain, Noise Figure Test Circuit

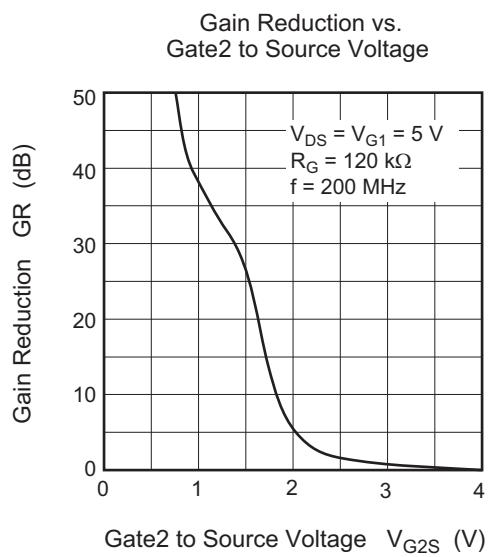
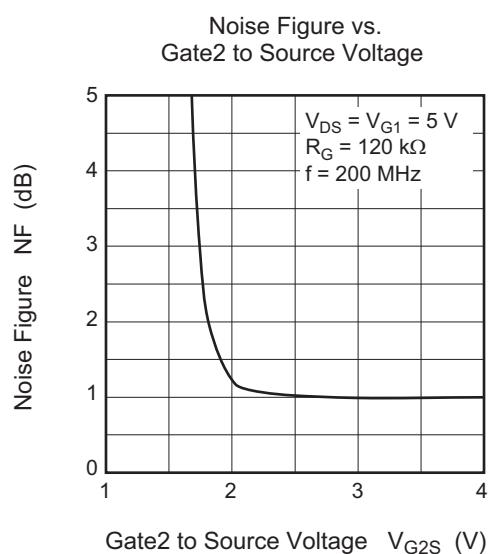
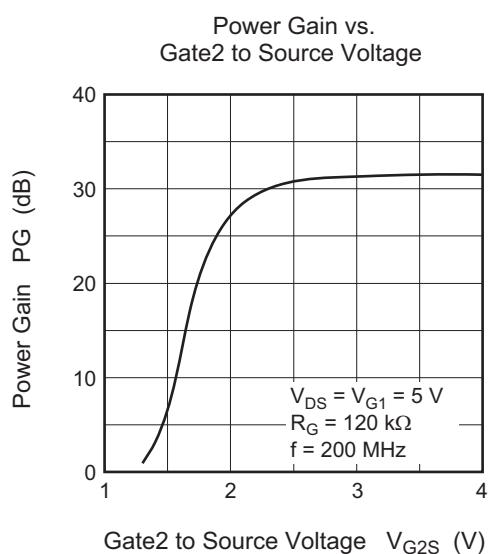
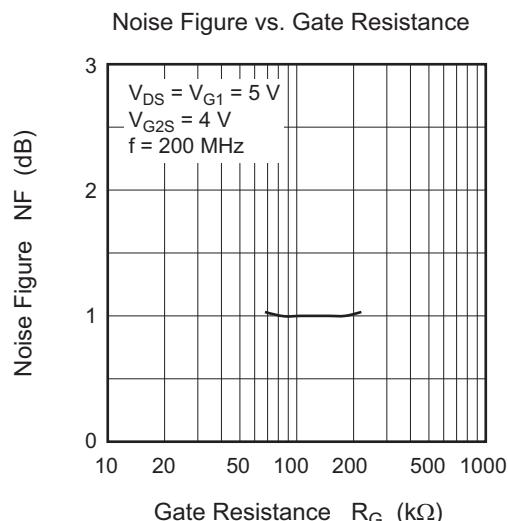
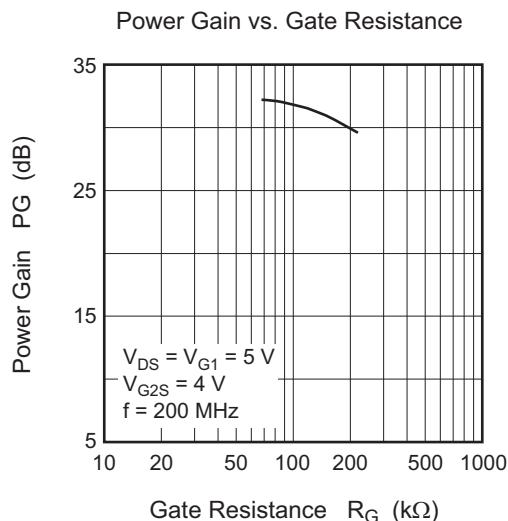


## Main Characteristics

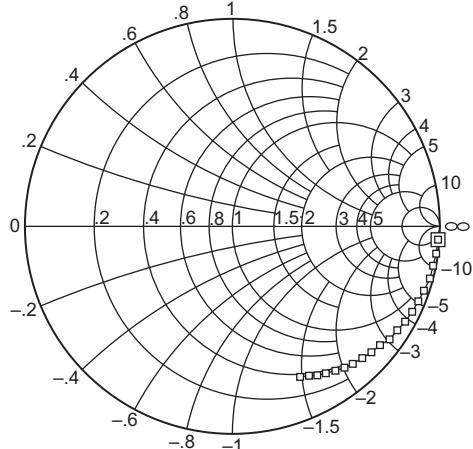


\* Value on the glass epoxy board (50 mm × 40 mm × 1 mm)



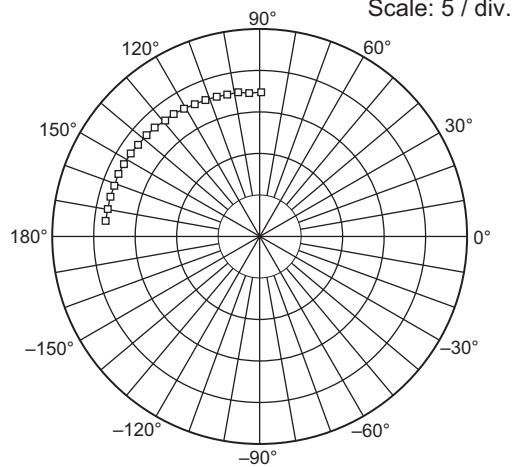


S11 Parameter vs. Frequency



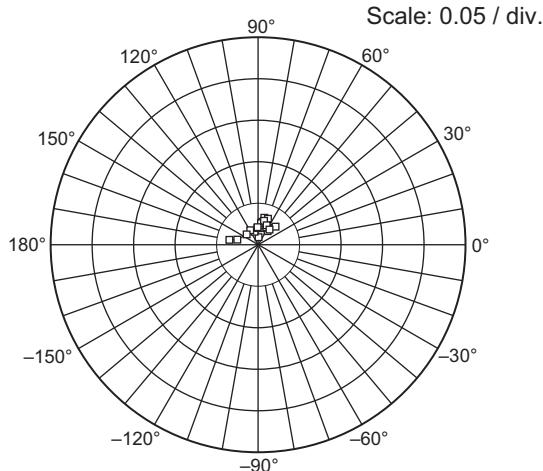
Test condition:  $V_{DS} = 5$  V,  $V_{G1} = 5$  V,  
 $V_{G2S} = 4$  V,  $R_G = 120$  k $\Omega$   
0.05 to 1.0 GHz (0.05 GHz step)

S21 Parameter vs. Frequency



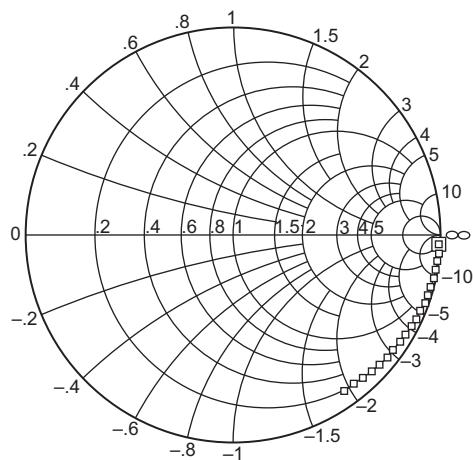
Test condition:  $V_{DS} = 5$  V,  $V_{G1} = 5$  V,  
 $V_{G2S} = 4$  V,  $R_G = 120$  k $\Omega$   
0.05 to 1.0 GHz (0.05 GHz step)

S12 Parameter vs. Frequency



Test condition:  $V_{DS} = 5$  V,  $V_{G1} = 5$  V,  
 $V_{G2S} = 4$  V,  $R_G = 120$  k $\Omega$   
0.05 to 1.0 GHz (0.05 GHz step)

S22 Parameter vs. Frequency



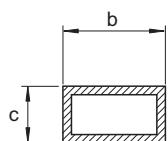
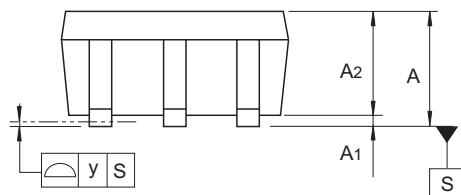
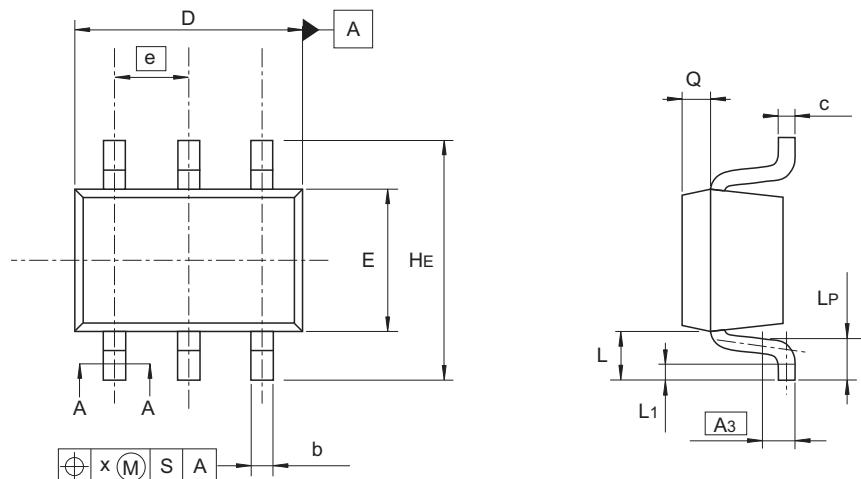
Test condition:  $V_{DS} = 5$  V,  $V_{G1} = 5$  V,  
 $V_{G2S} = 4$  V,  $R_G = 120$  k $\Omega$   
0.05 to 1.0 GHz (0.05 GHz step)

**S parameter**(V<sub>DS</sub> = 5 V, V<sub>G1</sub> = 5 V, V<sub>G2S</sub> = 4 V, R<sub>G</sub> = 120 kΩ, Z<sub>0</sub> = 50 Ω)

Freq. (MHz)	S11		S21		S12		S22	
	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
50	0.994	-3.7	3.73	175.3	0.002	88.4	0.992	-2.4
100	0.992	-7.6	3.72	170.7	0.003	107.7	0.996	-5.1
150	0.987	-11.1	3.72	166.1	0.004	54.7	0.992	-7.2
200	0.985	-14.8	3.70	161.7	0.004	62.4	0.990	-9.6
250	0.975	-18.6	3.71	157.0	0.005	81.1	0.990	-12.0
300	0.967	-21.9	3.69	152.9	0.005	83.3	0.984	-14.6
350	0.960	-25.4	3.68	148.1	0.004	65.3	0.982	-17.1
400	0.952	-28.9	3.65	143.8	0.006	68.8	0.982	-19.4
450	0.940	-32.2	3.64	138.9	0.006	77.6	0.972	-21.9
500	0.934	-35.7	3.62	134.7	0.006	69.3	0.971	-24.6
550	0.914	-38.8	3.58	130.0	0.006	77.0	0.965	-26.9
600	0.904	-42.1	3.58	125.9	0.006	45.7	0.959	-29.9
650	0.892	-45.4	3.55	121.4	0.005	66.8	0.955	-32.5
700	0.881	-48.8	3.52	116.9	0.004	52.5	0.948	-35.6
750	0.870	-51.5	3.51	112.5	0.004	93.5	0.949	-38.3
800	0.855	-54.4	3.49	107.9	0.004	92.7	0.941	-41.4
850	0.839	-57.5	3.47	103.7	0.004	121.0	0.936	-44.4
900	0.827	-60.3	3.48	99.3	0.004	140.2	0.929	-47.7
950	0.809	-62.8	3.43	95.0	0.005	167.7	0.921	-50.9
1000	0.796	-65.7	3.43	90.3	0.007	171.4	0.921	-54.5

## Package Dimensions

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
SC-88	PTSP0006JA-A	CMPAK-6 / CMPAK-6V	0.006



A-A Section

Reference Symbol	Dimensions in millimeters		
	Min	Nom	Max
A	0.8	—	1.1
A <sub>1</sub>	0	—	0.1
A <sub>2</sub>	0.8	0.9	1.0
A <sub>3</sub>	—	0.25	—
b	0.15	0.2	0.25
c	0.1	0.15	0.25
D	1.8	2.0	2.2
E	1.15	1.25	1.35
e	—	0.65	—
H <sub>E</sub>	2.0	2.1	2.2
L	0.3	—	0.7
L <sub>1</sub>	0.1	—	0.5
L <sub>P</sub>	0.2	—	0.6
x	—	—	0.05
y	—	—	0.05
Q	—	0.25	—

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**Ordering Information**

Part Name	Quantity	Shipping Container
TBB1016RMTL-E	3000 pcs	φ178mm reel, 8mm emboss taping
TBB1016RMTL-H		

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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